Smart High-Side Power Switch

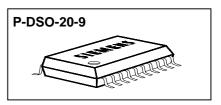
Two Channels: 2 x $60m\Omega$

Status Feedback

Product Summary

| Operating Voltage | V _{bb(on)} | 4.75. | 41V |
|----------------------|---------------------|---------------------|-----------------|
| | Active channels | one | two parallel |
| On-state Resistance | R _{ON} | $60 \text{m}\Omega$ | 30 m Ω |
| Nominal load current | I _{L(NOM)} | 4.0A | 6.0A |
| Current limitation | I _{L(SCr)} | 17A | 17A |

Package



General Description

- N channel vertical power MOSFET with charge pump, ground referenced CMOS compatible input and diagnostic feedback, monolithically integrated in Smart SIPMOS® technology.
- Fully protected by embedded protection functions

Applications

- µC compatible high-side power switch with diagnostic feedback for 5V, 12V and 24V grounded loads
- All types of resistive, inductive and capacitve loads
- Most suitable for loads with high inrush currents, so as lamps
- · Replaces electromechanical relays, fuses and discrete circuits

Basic Functions

- Very low standby current
- CMOS compatible input
- Improved electromagnetic compatibility (EMC)
- Fast demagnetization of inductive loads
- Stable behaviour at undervoltage
- Wide operating voltage range
- · Logic ground independent from load ground

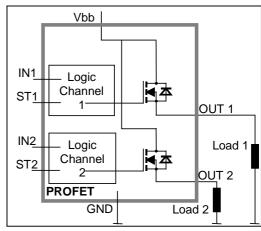
Protection Functions

- Short circuit protection
- Overload protection
- Current limitation
- Thermal shutdown
- Overvoltage protection (including load dump) with external resistor
- Reverse battery protection with external resistor
- Loss of ground and loss of V_{bb} protection
- Electrostatic discharge protection (ESD)

Diagnostic Function

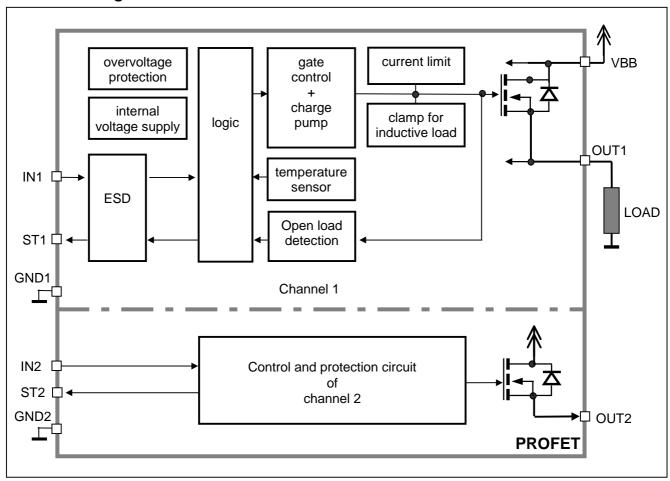
- · Diagnostic feedback with open drain output
- Open load detection in ON-state
- Feedback of thermal shutdown in ON-state

Block Diagram





Functional diagram



Pin Definitions and Functions

| Pin | Symbol | Function |
|--------|----------|--|
| 1,10, | V_{bb} | Positive power supply voltage. Design the |
| 11,12, | | wiring for the simultaneous max. short circuit |
| 15,16, | | currents from channel 1 to 2 and also for low |
| 19,20 | | thermal resistance |
| 3 | IN1 | Input 1,2, activates channel 1,2 in case of |
| 7 | IN2 | logic high signal |
| 17,18 | OUT1 | Output 1,2, protected high-side power output |
| 13,14 | OUT2 | of channel 1,2. Design the wiring for the max. |
| | | short circuit current |
| 4 | ST1 | Diagnostic feedback 1,2 of channel 1,2, |
| 8 | ST2 | open drain, low on failure |
| 2 | GND1 | Ground 1 of chip 1 (channel 1) |
| 6 | GND2 | Ground 2 of chip 2 (channel 2) |
| 5,9 | N.C. | Not Connected |

Pin configuration

| _ | | | _ |
|----------|-----|----|----------|
| V_{bb} | 1 • | 20 | V_{bb} |
| GND1 | 2 | 19 | V_{bb} |
| IN1 | 3 | 18 | OUT1 |
| ST1 | 4 | 17 | OUT1 |
| N.C. | 5 | 16 | V_{bb} |
| GND2 | 6 | 15 | V_{bb} |
| IN2 | 7 | 14 | OUT2 |
| ST2 | 8 | 13 | OUT2 |
| N.C. | 9 | 12 | V_{bb} |
| V_{bb} | 10 | 11 | V_{bb} |



Maximum Ratings at $T_i = 25$ °C unless otherwise specified

| Parameter | Symbol | Values | Unit |
|---|---------------------------|-------------------|---------------------------------------|
| Supply voltage (overvoltage protection see page 4) | $V_{ m bb}$ | 43 | V |
| Supply voltage for full short circuit protection $T_{j,\text{start}} = -40 \dots +150^{\circ}\text{C}$ | $V_{ m bb}$ | 24 | V |
| Load current (Short-circuit current, see page 5) | <i>I</i> ∟ | self-limited | Α |
| Load dump protection ¹⁾ $V_{\text{LoadDump}} = V_{\text{A}} + V_{\text{S}}$, $V_{\text{A}} = 13.5 \text{ V}$ $R_{\text{I}}^{(2)} = 2 \Omega$, $t_{\text{d}} = 200 \text{ ms}$; IN = low or high, each channel loaded with $R_{\text{L}} = 8.0 \Omega$, | V _{Load dump} 3) | 60 | V |
| Operating temperature range | $T_{\rm j}$ | -40+150 | °C |
| Storage temperature range | T_{stg} | -55+150 | |
| Power dissipation (DC) ⁴⁾ $T_a = 25$ °C: | P_{tot} | 3.7 | W |
| (all channels active) $T_a = 85$ °C: | | 1.9 | |
| Maximal switchable inductance, single pulse $V_{bb} = 12V$, $T_{j,start} = 150^{\circ}C^{4}$, | 7 | 10.0 | |
| $I_L = 4.0 \text{ A}$, $E_{AS} = 220 \text{ mJ}$, 0Ω one channel: | Z_{L} | 19.9 | mH |
| $I_L = 6.0 \text{ A}, E_{AS} = 540 \text{ mJ}, 0\Omega$ two parallel channels: | | 22.3 | |
| see diagrams on page 9 | 1 | | |
| Electrostatic discharge capability (ESD) IN: (Human Body Model) ST: out to all other pins shorted: acc. MIL-STD883D, method 3015.7 and ESD assn. std. S5.1-1993 | V _{ESD} | 1.0 4.0 8.0 | kV |
| R=1.5kΩ; C=100pF | 17 | 40 .40 | \ \ \ \ \ \ \ \ \ \ \ \ \ \ \ \ \ \ \ |
| Input voltage (DC) | V_{IN} | -10 +16 | V |
| Current through input pin (DC) | I _{IN} | ±2.0 | mA |
| Current through status pin (DC) | I _{ST} | ±5.0 | |
| see internal circuit diagram page 8 | | | |

Thermal Characteristics

| Parameter and Conditions | | Symbol | Values | | | Unit |
|--|----------------------|----------------|--------|-----|------|-------|
| | | | min | typ | Max | |
| Thermal resistance junction - soldering point ^{4),5)} | each channel: | R | | | 13.5 | K/W |
| , | | $R_{\rm thjs}$ | | | 13.3 | r\/vv |
| junction - ambient4) | one channel active: | $R_{\rm thja}$ | | 41 | | |
| | all channels active: | | | 34 | | |

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¹⁾ Supply voltages higher than $V_{bb(AZ)}$ require an external current limit for the GND and status pins (a 150 Ω resistor for the GND connection is recommended.

 $^{^{2)}}$ R_{I} = internal resistance of the load dump test pulse generator

³⁾ V_{Load dump} is setup without the DUT connected to the generator per ISO 7637-1 and DIN 40839

⁴⁾ Device on 50mm*50mm*1.5mm epoxy PCB FR4 with 6cm² (one layer, 70μm thick) copper area for V_{bb} connection. PCB is vertical without blown air. See page 14

⁵⁾ Soldering point: upper side of solder edge of device pin 15. See page 14



Electrical Characteristics

| two parallel channels, $T_{\rm j}=150^{\circ}{\rm C}$: see diagram, page 10 Nominal load current one channel active: $I_{\rm Li}$ two parallel channels active: Device on PCB ⁶), $T_{\rm a}=85^{\circ}{\rm C}$, $T_{\rm j}\leq 150^{\circ}{\rm C}$ Output current while GND disconnected or pulled up; $V_{\rm bb}=30~{\rm V}$, $V_{\rm IN}=0$, see diagram page 8; (not tested specified by design) Turn-on time ⁷) IN \Box to 90% $V_{\rm OUT}$: $t_{\rm oi}$ Turn-off time IN \Box to 10% $V_{\rm OUT}$: $t_{\rm oi}$ | | min | typ | Max | |
|---|-------------------------|------|-----|-----|------|
| On-state resistance (V_{bb} to OUT); $I_L = 2 \text{ A}, V_{bb} \ge 7 \text{V}$ each channel, $T_j = 25 ^{\circ}\text{C}$: $T_j = 150 ^{\circ}\text{C}$: two parallel channels, $T_j = 25 ^{\circ}\text{C}$: see diagram, page 10 Nominal load current one channel active: two parallel channels active: Device on PCB ⁶), $T_a = 85 ^{\circ}\text{C}$, $T_j \le 150 ^{\circ}\text{C}$ Output current while GND disconnected or pulled up; $V_{bb} = 30 \text{ V}, V_{IN} = 0$, see diagram page 8; (not tested specified by design) Turn-on time ⁷) IN V_{color} to 90% V_{color} : V_{color} Turn-off time IN V_{color} to 10% V_{color} : V_{color} Slew rate on V_{color} ? | | · | • | | |
| each channel, $T_{\rm j}=25^{\circ}{\rm C}$: $T_{\rm j}=150^{\circ}{\rm C}$: two parallel channels, $T_{\rm i}=25^{\circ}{\rm C}$: see diagram, page 10 Nominal load current one channel active: two parallel channels active: Device on PCB ⁶), $T_{\rm a}=85^{\circ}{\rm C}$, $T_{\rm j}\leq150^{\circ}{\rm C}$ Output current while GND disconnected or pulled up; $V_{\rm bb}=30~{\rm V},~V_{\rm IN}=0$, see diagram page 8; (not tested specified by design) Turn-on time ⁷) IN \Box to 90% $V_{\rm OUT}$: $t_{\rm ol}$ Turn-off time IN \Box to 10% $V_{\rm OUT}$: $t_{\rm ol}$ Slew rate on $V_{\rm out}$: $V_{\rm out}$ | | | | | |
| two parallel channels, $T_{\rm j}=150^{\circ}{\rm C}$: see diagram, page 10 Nominal load current one channel active: $I_{\rm Li}$ two parallel channels active: Device on PCB ⁶), $T_{\rm a}=85^{\circ}{\rm C}$, $T_{\rm j}\leq150^{\circ}{\rm C}$ Output current while GND disconnected or pulled up; $V_{\rm bb}=30~{\rm V}$, $V_{\rm IN}=0$, see diagram page 8; (not tested specified by design) Turn-on time ⁷) IN \Box to 90% $V_{\rm OUT}$: $t_{\rm ol}$ Turn-off time $I_{\rm L}=12~{\rm \Omega}$ Slew rate on $I_{\rm col}$ | | | | | |
| two parallel channels, $T_{\rm i} = 25^{\circ}{\rm C}$: see diagram, page 10 Nominal load current one channel active: $I_{\rm Li}$ two parallel channels active: Device on PCB ⁶), $T_{\rm a} = 85^{\circ}{\rm C}$, $T_{\rm j} \le 150^{\circ}{\rm C}$ Output current while GND disconnected or pulled up; $V_{\rm bb} = 30 \text{ V}$, $V_{\rm IN} = 0$, see diagram page 8; (not tested specified by design) Turn-on time ⁷) IN \square to 90% $V_{\rm OUT}$: $t_{\rm OI}$ Turn-off time $R_{\rm L} = 12 \Omega$ Slew rate on $T_{\rm C}$ | R_{ON} | | 50 | 60 | mΩ |
| see diagram, page 10 Nominal load current one channel active: I_{L} two parallel channels active: Device on PCB ⁶), $T_a = 85^{\circ}\text{C}$, $T_j \le 150^{\circ}\text{C}$ Output current while GND disconnected or pulled up; $V_{DD} = 30 \text{ V}$, $V_{IN} = 0$, see diagram page 8; (not tested specified by design) Turn-on time ⁷) IN to 90% V_{OUT} : t_{OI} Turn-off time IN to 10% V_{OUT} : t_{OI} Slew rate on t_{OI} ? | | | 100 | 120 | |
| two parallel channels active: $\frac{\text{Device on PCB}^6), \ T_a = 85^{\circ}\text{C}, \ T_j \leq 150^{\circ}\text{C}}{\text{Output current while GND disconnected or pulled up;}} \text{I_{Li}} \\ \text{$V_{\text{bb}} = 30 \ V, \ $V_{\text{IN}} = 0$,} \\ \text{$\text{see diagram page 8; (not tested specified by design)}} \\ \text{Turn-on time^7} \text{$\text{IN} \bot} \text{$\text{to 90\% V_{OUT}:}} t_{\text{Ol}} \\ \text{$\text{Turn-off time}} \text{$\text{IN} \bot} \text{$\text{to 10\% V_{OUT}:}} t_{\text{Ol}} \\ \text{Slew rate on^7)} \text{$\text{do } Slew rate on^7)} \\ \text{$\text{Turn-off time}} \text{$\text{IN} \bot} \text{$\text{do } Slew rate on^7)} \\ \text{Slew rate on^7)} \text{$\text{do } Slew rate on^7)} \\ \text{$\text{Turn-off time}} \text{$\text{IN} \bot} \text{$\text{do } Slew rate on^7)} \\ \text{$\text{Turn-off time}} \text{$\text{IN} \bot} \text{$\text{do } Slew rate on^7)} \\ \text{$\text{Turn-off time}} \text{$\text{IN} \bot} \text{$\text{do } Slew rate on^7)} \\ \text{$\text{Turn-off time}} \text{$\text{IN} \bot} \text{$\text{do } Slew rate on^7)} \\ \text{$\text{Turn-off time}} \text{$\text{IN} \bot} \text{$\text{do } Slew rate on^7)} \\ \text{$\text{Turn-off time}} \text{$\text{IN} \bot} \text{$\text{do } Slew rate on^7)} \\ \text{$\text{Turn-off time}} \text{$\text{IN} \bot} \text{$\text{do } Slew rate on^7)} \\ \text{$\text{Turn-off time}} \text{$\text{IN} \bot} \text{$\text{do } Slew rate on^7)} \\ \text{$\text{Turn-off time}} \text{$\text{IN} \bot} \text{$\text{do } Slew rate on^7)} \\ \text{$\text{Turn-off time}} \text{$\text{IN} \bot} \text{$\text{do } Slew rate on^7)} \\ \text{$\text{Turn-off time}} \text{$\text{IN} \bot} \text{$\text{do } Slew rate on^7)} \\ \text{$\text{Turn-off time}} \text{$\text{IN} \bot} \text{$\text{do } Slew rate on^7)} \\ \text{$\text{Turn-off time}} \text{$\text{IN} \bot} \text{$\text{do } Slew rate on^7)} \\ \text{$\text{Turn-off time}} \text{$\text{Loo} Slew rate on^7)} \\ $\text{T$ | | | 25 | 30 | |
| Device on PCB ⁶), $T_a = 85^{\circ}\text{C}$, $T_j \le 150^{\circ}\text{C}$ Output current while GND disconnected or pulled up; $V_{\text{bb}} = 30 \text{ V}$, $V_{\text{IN}} = 0$, see diagram page 8; (not tested specified by design) Turn-on time ⁷) IN to 90% V_{OUT} : t_{OI} Turn-off time IN to 10% V_{OUT} : t_{OI} Slew rate on 7) | $I_{L(NOM)}$ | 3.6 | 4.0 | | Α |
| Output current while GND disconnected or pulled up; $V_{\text{bb}} = 30 \text{ V}$, $V_{\text{IN}} = 0$, see diagram page 8; (not tested specified by design) Turn-on time ⁷⁾ IN to 90% V_{OUT} : t_{old} Turn-off time IN to 10% V_{OUT} : t_{old} Slew rate on 7) | , , | 5.5 | 6.0 | | |
| Vbb = 30 V, V_{IN} = 0, see diagram page 8; (not tested specified by design) Turn-on time ⁷ IN \perp to 90% V_{OUT} : t_{ol} Turn-off time IN \perp to 10% V_{OUT} : t_{ol} Slew rate on 7) | | | | | |
| Turn-on time ⁷⁾ Turn-off time $R_{L} = 12 \Omega$ Slew rate on 7) IN \Box to 90% V_{OUT} : t_{OI} to 10% V_{OUT} : t_{OI} d | I _{L(GNDhigh)} | | | 2 | mA |
| Turn-off time IN \Box to 10% V_{OUT} : t_{ol} $R_{\text{L}} = 12 \Omega$ Slew rate on T_{OUT} d | | | | | |
| $R_{\rm L} = 12 \Omega$ Slew rate on 7) d | <i>t</i> on | 30 | 100 | 200 | μs |
| Slew rate on 7) d | t _{off} | 30 | 100 | 200 | |
| | | | | | |
| 10 to 30% $V_{OUT} R_1 = 12.0$ | d V/dt _{on} | 0.1 | | 1 | V/μs |
| 10 10 00 70 1001; 712 12 12: | | | | | |
| Slew rate off 7) -0 70 to 40% V_{OUT} , $R_{\text{L}} = 12 \Omega$: | -d V/dt _{off} | 0.1 | | 1 | V/µs |
| Operating Parameters Operating voltage Tip 40 1/2 | | 1 75 | | 41 | V |

| Operating randineters | | | | | | |
|---|-----------------------------------|----------------------|------|-----|-----|----|
| Operating voltage | Tj=-40 | $V_{\rm bb(on)}$ | 4.75 | | 41 | V |
| | T _j =25150°C: | | | | 43 | |
| Overvoltage protection ⁸⁾ | $T_{\rm j}$ =-40°C: | $V_{\rm bb(AZ)}$ | 41 | - | - | V |
| $I_{bb} = 40 \text{ mA}$ | $T_{\rm j}$ =25150°C: | | 43 | 47 | 52 | |
| Standby current ⁹⁾ | <i>T</i> _j =-40°C25°C: | I _{bb(off)} | | 10 | 18 | μΑ |
| $V_{IN} = 0$; see diagram page 10 | $T_{\rm j}$ =150°C: | | | | 50 | |
| Leakage output current (included in Ibb(off)) | | I _{L(off)} | | 1 | 10 | μΑ |
| $V_{IN} = 0$ | | | | | | |
| Operating current ¹⁰⁾ , $V_{IN} = 5V$, | | | | | | |
| $I_{\text{GND}} = I_{\text{GND1}} + I_{\text{GND2}},$ | one channel on: | I _{GND} | | 0.8 | 1.5 | mΑ |
| | two channels on: | | | 1.6 | 3.0 | |

⁶⁾ Device on 50mm*50mm*1.5mm epoxy PCB FR4 with 6cm² (one layer, 70μm thick) copper area for V_{bb} connection. PCB is vertical without blown air. See page 14

⁷⁾ See timing diagram on page 11.

Supply voltages higher than $V_{bb(AZ)}$ require an external current limit for the GND and status pins (a 150 Ω resistor for the GND connection is recommended). See also $V_{ON(CL)}$ in table of protection functions and circuit diagram on page 8.

⁹⁾ Measured with load; for the whole device; all channels off

¹⁰⁾ Add I_{ST} , if $I_{ST} > 0$

Parameter and Conditions, each of the two channels

BTS 728 L2

Values

| didifficient difficultions, each of the two chamles | | Cyllibol | | Values | | Oilit |
|---|-------------------------------|----------------------|-----|--------|-----|-------|
| at T _j = -40+150°C, V_{bb} = 12 V unless oth | erwise specified | | min | typ | Max | |
| Protection Functions | | | | | | |
| Current limit, (see timing diagrams, pag | e 12) | | | | | |
| | <i>T</i> _j =-40°C: | $I_{L(lim)}$ | 21 | 28 | 36 | Α |
| | T _j =25°C: | | 17 | 22 | 31 | |
| | T _i =+150°C: | | 12 | 16 | 24 | |
| Repetitive short circuit current limit, | • | | | | | |
| $T_{\rm i} = T_{\rm it}$ | each channel | I _{L(SCr)} | | 17 | | Α |
| • • | arallel channels | () | | 17 | | |
| (see timing diagrams, page 12) | | | | | | |
| Initial short circuit shutdown time $T_{j,start} = 25^{\circ}C$: | | t _{off(SC)} | | 2.4 | | ms |
| (see timing diagrams on page 12) | | | | | | |
| Output clamp (inductive load switch off) ¹¹⁾ | | | | | | V |
| at $VON(CL) = Vbb - VOUT$, $IL = 40 \text{ mA}$ | $T_{\rm j}$ =-40°C: | $V_{ON(CL)}$ | 41 | | | |
| | =25°C150°C: | | 43 | 47 | 52 | |
| Thermal overload trip temperature | | T_{jt} | 150 | | | °C |
| Thermal hysteresis | | $\Delta T_{\rm jt}$ | | 10 | | K |
| | | | | | | |
| Reverse Battery | | | | | | |
| Reverse battery voltage 12) | | - V _{bb} | | | 32 | V |
| Drain-source diode voltage (Vout > V | bb) | -V _{ON} | | 600 | | mV |
| $I_L = -4.0 \text{ A}, T_j = +150^{\circ}\text{C}$ | | | | | | |

Symbol

¹¹⁾ If channels are connected in parallel, output clamp is usually accomplished by the channel with the lowest VON(CL)

Requires a 150 Ω resistor in GND connection. The reverse load current through the intrinsic drain-source diode has to be limited by the connected load. Power dissipation is higher compared to normal operating conditions due to the voltage drop across the drain-source diode. The temperature protection is not active during reverse current operation! Input and Status currents have to be limited (see max. ratings page 3 and circuit page 8).

BTS 728 L2

| | | T | | | 5107 | |
|---|------------------------------|---------------------------|-----|--------|------|------|
| Parameter and Conditions, each of the two channels | | Symbol | | Values | | Unit |
| at $T_j = -40+150$ °C, $V_{bb} = 12$ V unless of | otherwise specified | | min | typ | Max | |
| Diagnostic Characteristics | | | | | | |
| Open load detection current, (on-o | condition) | | | | | |
| | each channel | I _{L (OL)} | 10 | | 500 | mΑ |
| Input and Status Feedback ¹³⁾ | | | 0.5 | 2.5 | 0 | 1-0 |
| Input resistance (see circuit page 8) | | R_{l} | 2.5 | 3.5 | 6 | kΩ |
| Input turn-on threshold voltage | | $V_{IN(T+)}$ | 1.7 | | 3.2 | V |
| Input turn-off threshold voltage | | $V_{IN(T-)}$ | 1.5 | | | V |
| Input threshold hysteresis | | $\Delta V_{\text{IN(T)}}$ | | 0.5 | | V |
| Off state input current | $V_{IN} = 0.4 \text{ V}$: | I _{IN(off)} | 1 | | 50 | μΑ |
| On state input current | $V_{IN} = 5 \text{ V}$: | I _{IN(on)} | 20 | 50 | 90 | μΑ |
| Delay time for status with open load after switch off; (see diagram on page 13) | | $t_{ m d(ST~OL4)}$ | 100 | 520 | 900 | μs |
| Otation autout (amana dualia) | | | | | | |
| Status output (open drain) | | | | | | |
| Zener limit voltage | $I_{ST} = +1.6 \text{ mA}$: | $V_{\rm ST(high)}$ | 5.4 | 6.1 | | V |

 $^{^{\}rm 13)}\,$ If ground resistors ${\rm R}_{\rm GND}$ are used, add the voltage drop across these resistors.



Truth Table

| Channel 1 | Input 1 | Output 1 | Status 1 |
|-----------|---------|----------|-----------|
| Channel 2 | Input 2 | Output 2 | Status 2 |
| | level | level | BTS 728L2 |
| Normal | L | L | Н |
| operation | Н | Н | Н |
| Open load | L | Z | Н |
| | Н | Н | L |
| Overtem- | L | L | Н |
| perature | Н | L | L |

L = "Low" Level

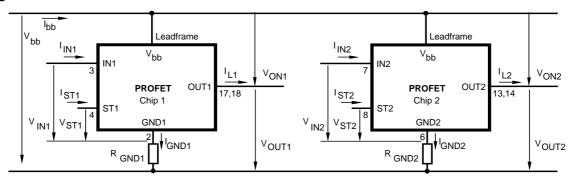
X = don't care

Z = high impedance, potential depends on external circuit

H = "High" Level Status signal valid after the time delay shown in the timing diagrams

Parallel switching of channel 1 and 2 is easily possible by connecting the inputs and outputs in parallel. The status outputs ST1 and ST2 have to be configured as a 'Wired OR' function with a single pull-up resistor.

Terms

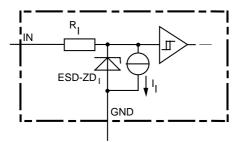


Leadframe (V_{bb}) is connected to pin 1,10,11,12,15,16,19,20

External R_{GND} optional; two resistors R_{GND1}, R_{GND2} = 150 Ω or a single resistor R_{GND} = 75 Ω for reverse battery protection up to the max. operating voltage.

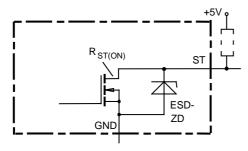
SIEMENS

Input circuit (ESD protection), IN1 or IN2



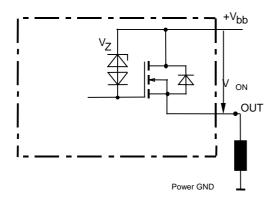
The use of ESD zener diodes as voltage clamp at DC conditions is not recommended.

Status output, ST1 or ST2



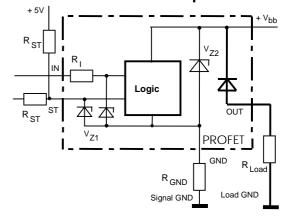
ESD-Zener diode: 6.1 V typ., max 5.0 mA; $R_{ST(ON)}$ < 375 Ω at 1.6 mA. The use of ESD zener diodes as voltage clamp at DC conditions is not recommended.

Inductive and overvoltage output clamp, OUT1 or OUT2



VON clamped to VON(CL) = 47 V typ.

Overvolt. and reverse batt. protection



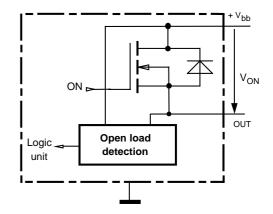
 $V_{Z1} = 6.1 \text{ V typ.}, \ V_{Z2} = 47 \text{ V typ.}, \ R_{GND} = 150 \ \Omega, \ R_{ST} = 15 \ k\Omega, \ R_{I} = 3.5 \ k\Omega \ typ.$

In case of reverse battery the load current has to be limited by the load. Temperature protection is not active

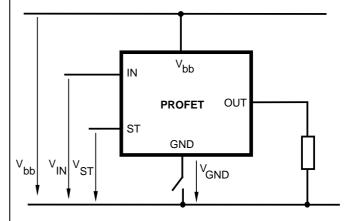
Open-load detection OUT1 or OUT2

ON-state diagnostic

Open load, if $V_{\text{ON}} < R_{\text{ON}} \cdot I_{\text{L(OL)}}$; IN high



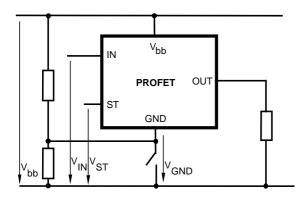
GND disconnect



Any kind of load. In case of IN = high is $V_{OUT} \approx V_{IN} - V_{IN}(T+)$. Due to $V_{GND} > 0$, no $V_{ST} = low$ signal available.

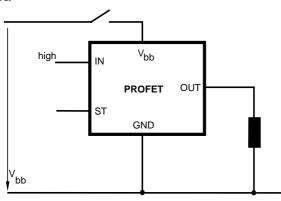


GND disconnect with GND pull up



Any kind of load. If $V_{GND} > V_{IN} - V_{IN(T+)}$ device stays off Due to $V_{GND} > 0$, no $V_{ST} = low$ signal available.

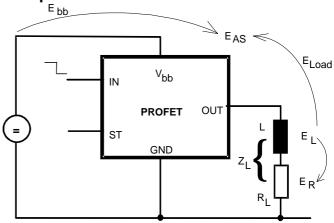
V_{bb} disconnect with energized inductive load



For inductive load currents up to the limits defined by Z_L (max. ratings and diagram on page 9) each switch is protected against loss of $V_{\mbox{bb}}$.

Consider at your PCB layout that in the case of Vbb disconnection with energized inductive load all the load current flows through the GND connection.

Inductive load switch-off energy dissipation



Energy stored in load inductance:

$$E_{L} = \frac{1}{2} \cdot L \cdot I_{L}^{2}$$

While demagnetizing load inductance, the energy dissipated in PROFET is

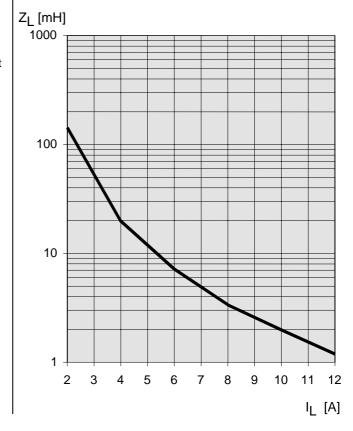
$$\textit{E}_{\text{AS}} = \mathsf{E}_{\text{bb}} + \mathsf{E}_{\mathsf{L}} - \mathsf{E}_{\mathsf{R}} = \int \mathsf{V}_{\mathsf{ON}(\mathsf{CL})} \cdot \mathsf{i}_{\mathsf{L}}(\mathsf{t}) \; \mathsf{dt},$$

with an approximate solution for $R_L > 0 \Omega$:

$$E_{\text{AS}} = \frac{I_{\text{L}} \cdot L}{2 \cdot R_{\text{L}}} (V_{\text{bb}} + |V_{\text{OUT(CL)}}|) \ ln \ (1 + \frac{I_{\text{L}} \cdot R_{\text{L}}}{|V_{\text{OUT(CL)}}|})$$

Maximum allowable load inductance for a single switch off (one channel)⁴⁾

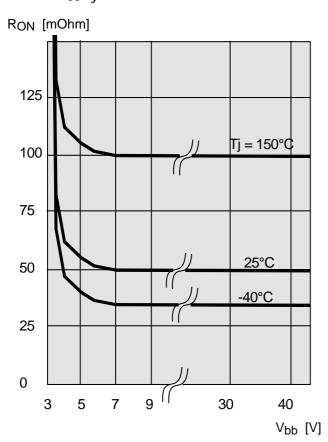
$$L = f(I_L)$$
; T_{j,start} = 150°C, V_{bb} = 12 V, R_L = 0 Ω





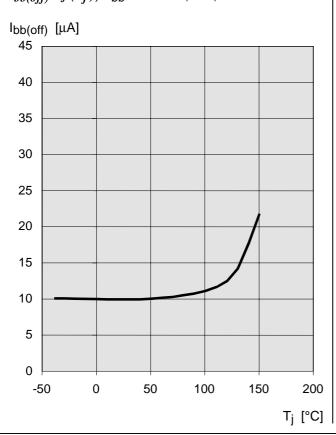
Typ. on-state resistance

 $R_{ON} = f(V_{bb}, T_j); I_L = 2 A, IN = high$



Typ. standby current

 $I_{bb(off)} = f(T_j); V_{bb} = 9...34 \text{ V}, \text{IN1,2} = \text{low}$



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Timing diagrams

Both channels are symmetric and consequently the diagrams are valid for channel 1 and channel 2

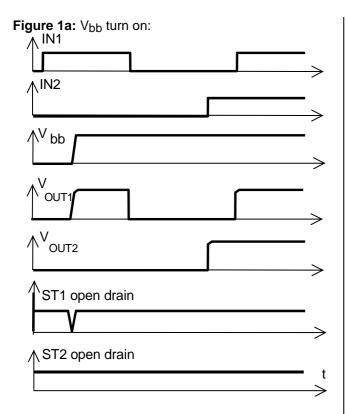


Figure 2a: Switching a resistive load, turn-on/off time and slew rate definition:

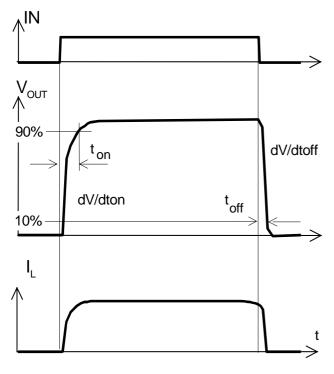
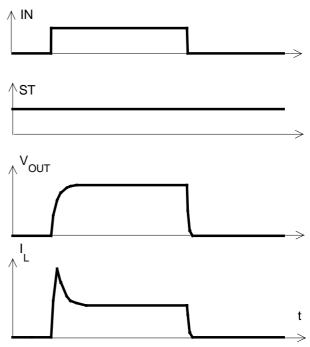
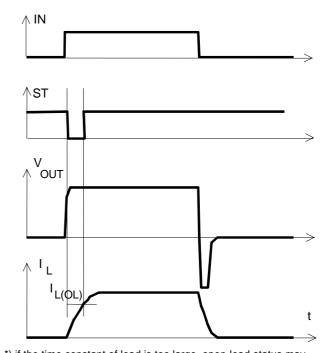


Figure 2b: Switching a lamp:



The initial peak current should be limited by the lamp and not by the current limit of the device.

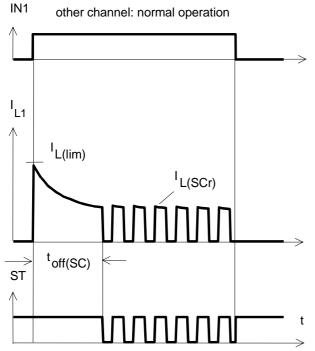
Figure 2c: Switching an inductive load



 $\ensuremath{^{\star}}\xspace$) if the time constant of load is too large, open-load-status may occur

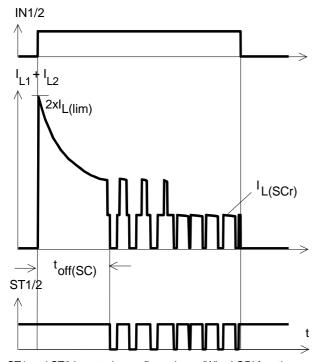
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Figure 3a: Turn on into short circuit: shut down by overtemperature, restart by cooling



Heating up of the chip may require several milliseconds, depending on external conditions

Figure 3b: Turn on into short circuit: shut down by overtemperature, restart by cooling (two parallel switched channels 1 and 2)



ST1 and ST2 have to be configured as a 'Wired OR' function ST1/2 with a single pull-up resistor.

Figure 4a: Overtemperature: Reset if $T_i < T_{it}$

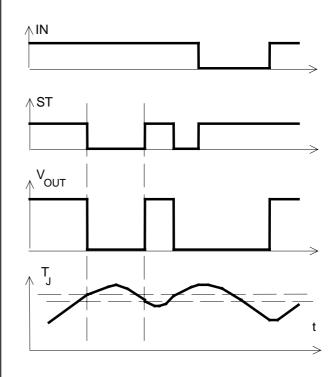


Figure 5a: Open load: detection in ON-state, open load occurs in on-state

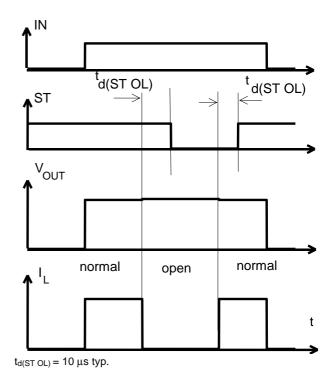
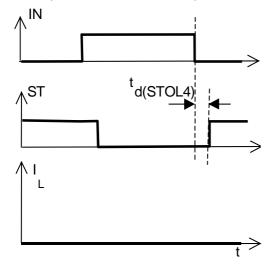




Figure 5b: Open load: turn on/off to open load



Package and Ordering Code

Standard: P-DSO-20-9

| Sales Code | BTS 728 L2 |
|---------------|-----------------|
| Ordering Code | Q67060-S7014-A2 |

All dimensions in millimetres

0.35x45°
7.8-02

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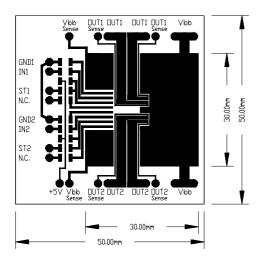
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Definition of soldering point with temperature T_s: upper side of solder edge of device pin 15.



Printed circuit board (FR4, 1.5mm thick, one layer $70\mu m$, $6cm^2$ active heatsink area) as a reference for max. power dissipation P_{tot} , nominal load current $I_{L(NOM)}$ and thermal resistance R_{thia}



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